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High-excitation effect on photoluminescence of sol-gel ZnO nanopowder

C. H. Chia,¹,a) Y. J. Lai,¹ T. C. Han,¹ J. W. Chiou,¹ Y. M. Hu,¹ and W. C. Chou²

¹Department of Applied Physics, National University of Kaohsiung, Kaohsiung 81148, Taiwan
²Department of Electrophysics, National Chiao Tung University, Hsin-Chu 30010, Taiwan

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We studied the power-dependent photoluminescence of ZnO nanopowder grown by sol-gel method at low temperature. At moderate optical pumping intensity, two nonlinear emission bands due to the radiative recombination of free biexciton and the inelastic exciton–exciton scattering were detected. We found that the threshold of the excitation density for the emergence of the nonlinear emission bands is low (<18 W/cm²) in sol-gel ZnO nanopowders. © 2010 American Institute of Physics. [doi:10.1063/1.3327338]

It is well established that the interaction between two excitons will lead to the formation of biexcitons and the inelastic scattering between excitons. These exciton–exciton interactions will cause the emergence of nonlinear emission lines at the low-energy side of excitonic emission.¹–³ ZnO has been attracting much attention due to its potential applications in ultraviolet optoelectronics devices. The large exciton binding energy of ZnO (60 meV) (Ref. 6) enables the utilization of exciton-related transitions in light-emitting devices even at room-temperature (RT). In ZnO quantum well, the binding energy of biexcitons and the exciton–exciton scattering efficiency enhance significantly.⁷,⁸ In particular, the biexciton binding energy in ZnO quantum well can be comparable to thermal energy of RT,⁸ indicating the possibility of biexciton lasing at even at RT.⁹,¹⁰ Therefore, study of photoluminescence (PL) of the highly excited ZnO is important.

Sol-gel technique is much cheaper and easier to grow large area of ZnO films than much sophisticated techniques. The sol-gel ZnO thin films have already been realized in a transparent p-n junction diodes¹¹ and transistors.¹² For a large use of sol-gel ZnO for optoelectronic devices, a better understanding of the PL mechanisms in sol-gel ZnO under high-excitation condition is necessary. In this letter, we report the PL of highly excited sol-gel ZnO nanopowders. At moderate optical pumping intensity, two nonlinear emission bands due to the radiative recombination of free biexciton and the inelastic exciton–exciton scattering were found.

The ZnO nanopowders were grown from aqueous solution prepared using zinc nitrate hexahydrate [Zn(NO₃)₂·6H₂O] as the starting material, de-ionized water as the solvent, and citric acid (C₆H₈O₇) as the stabilizer. The precursor solution was mixed thoroughly with a magnetic stirrer in 80 °C water bath until the formation of a sol. The sol was preheated in a furnace at 120 °C for 12 h to evaporate the solvent and remove the organic residuals. The powders obtained from the dried sol were then annealed at 600 °C for 2 h at ambient air. The crystalline size of the ZnO nanopowders was estimated to be about 30 nm by Sherrer’s equation from the result of x-ray diffraction method using a monochromated x-ray beam CuKα=0.154 nm. No quantum confinement effect of excitons is expected in the sample.

The PL spectra were measured by a 32-cm-long monochromatized and a charge-coupled device camera. The pump source for the low-excitation spectra was mercury lamp. The excitation-power dependence of the PL spectra was measured by the 266 nm-line of a neodymium-doped yttrium aluminium garnet (Nd:YAG) laser. The pulsed laser has a pulse width of 10 ns and a repetition rate of 20 Hz. The reflection spectrum was obtained by using a deuterium-tungsten lamp. A closed cycle refrigerator was used to perform the T-dependent measurement.

Figure 1 shows the low-T spectra of ZnO nanopowders. The reflection spectrum and low-excitation PL spectrum (80 µW/cm²) were shown in Fig. 1(a). The reflection spectrum shows three distinct anomalies in the exciton resonance region, the minimum energies of which are 3.378, 3.384, and 3.436 eV. These can be assigned to the ground states of A, B,

![FIG. 1.](image-url)

FIG. 1. (a) Low-excitation PL spectrum and reflection spectrum of ZnO nanopowders taken at T=12 K. FXA, FXB, and FXC represented the energies of free A, B, and C excitons, respectively. The origins of the emission bands D²X, D1, D2, and D3 are given in text. (b) Evolution of PL spectra in ZnO nanopowders with increasing excitation intensity taken at 12 K. BX and X–X emission lines are due to the radiative recombination of biexcitons and inelastic exciton–exciton scattering.

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a)Author to whom all correspondence should be addressed. Electronic mail: chchia@nuk.edu.tw.
and C free exciton (FX), respectively. It is well known that the allowed selection rule for the optical transitions of A and B excitons is $E \perp c$, the existence of C-exciton structure in the reflectance spectrum indicates the c-axis orientation is different from grain to grain in our sample.

The radiative recombination of donor-bound exciton $D\beta X$ (3.362 eV) dominates the low-excitation PL spectrum. Three emission bands were found at the low-energy side of the main PL band. The energetic positions of D1, D2, and D3 emission peak are 3.334, 3.313, and 3.297 eV, respectively. The D1 and D2 emissions can be attributed to the transitions related to the structural defects, whereas the D3 band may due to the two-electron satellite of the $D\beta X$. In Fig. 1(b), the evolution of PL band as a function of excitation power ($I_{\text{EXC}}$) was shown. As the $I_{\text{EXC}}$ increases, two emission bands with peak energies of 3.361 eV (denotes as $BX$) and 3.315 eV (denotes as $X-X$), dominate the PL spectra. Although the energetic positions of these two bands are almost the same as that of the $D\beta X$ and D2, we believe that the emissions mainly originated from the radiative recombination of biexcitons (BX) and inelastic exciton–exciton ($X-X$) scattering for the high $I_{\text{EXC}}$ condition, as will be verified later. A shoulder appears at the high-energy side of the $BX$ band as the $I_{\text{EXC}}$ increases. This shoulder could be attributed to the transition of FXs because the bound exciton states saturate under the high $I_{\text{EXC}}$ condition.

Figure 2(a) shows the PL peak intensities of the $BX$ ($I_{BX}$) and $X-X$ ($I_{X-X}$) bands as a function of $I_{\text{EXC}}$ (with maximum value of 342 W/cm$^2$). We found that the $I_{BX}$ and $I_{X-X}$ increase superlinearly with the $I_{\text{EXC}}$, with $I_{BX} \propto I_{\text{EXC}}^{1.4}$ and $I_{X-X} \propto I_{\text{EXC}}^{1.7}$. The biexcitonic transition energy is given by $E_{\beta X} = 2E_{FX} - \frac{E_{FX}^b}{E_{FX}}$, with $E_{FX}$ and $E_{FX}^b$ being the free exciton energy and the free biexciton binding energy. We can obtain the lowest resonance energy of A-exciton states by subtracting the longitudinal-transverse splitting energy (2 meV) (Ref. 6) from the reflectance minimum energy of A-exciton (3.378 eV) in Fig. 1(a). The $E_{\beta X}$ of ZnO is about 15 meV. Therefore, the resonance energy of biexciton transitions should be 3.361 eV. Also, at high $I_{\text{EXC}}$, the inelastic collision between two excitons could result an exciton excited into a continuum states, and a photon with energy given by $E_{X-X} = E_{FX} - E_{FX}^b - 1.5k_BT_{\text{th}}$, with $E_{FX}$ (60 meV) and $k_B$ being the free exciton binding energy and the Boltzmann constant. At 10 K, the thermal energy is about 1 meV. Therefore, the $E_{X-X}$ is 3.315 eV. The measured peak energies of the $BX$ and $X-X$ bands coincide well with the calculations. Since the $I_{BX}$ and $I_{X-X}$ depends superlinearly on the $I_{\text{EXC}}$, we believe that the dominant PL bands are due to the radiative recombination of biexcitons and inelastic exciton–exciton scattering under the high $I_{\text{EXC}}$ condition.

Figure 2(b) shows the evolution of the peak intensities of $D2$ and $D\beta X$, as a function of $I_{\text{EXC}}$ (with maximum value of 80 $\mu$W/cm$^2$). We used the mercury lamp as an excitation source and a variable neutral density filter to monitor the pumping intensity. Both of them show a linear dependence on $I_{\text{EXC}}$. Therefore, at extremely low-excitation, it is reasonable to assign the $D2$ and $D\beta X$ bands to structural defects and donor-bound excitons, respectively. However, the $BX$ and $X-X$ bands overlapped the $D2$ and $D\beta X$ bands at the high excitation density. This also explains why the $I_{BX}$ and $I_{X-X}$ do not follow the quadratic dependence on $I_{\text{EXC}}$.

Figure 3 shows the $T$-dependent PL of ZnO nanopowders ($I_{\text{EXC}} = 139$ W/cm$^2$). As $T$ increases, all of the emission band redshift. We can observe the intensity of the biexciton transition gradually decreases, and finally diminishes at $T = 180$ K, of which the thermal energy is corresponding to the $E_{\beta X} \sim 15$ meV.

The PL of ZnO associated with various exciton transitions has been investigated by several research groups. We note that the threshold-$I_{\text{EXC}}$ for the emergence of the nonlinear $BX$ and $X-X$ emission bands is at least lower than 18 W/cm$^2$. The threshold-$I_{\text{EXC}}$ for the emergence of $BX$ band might be comparable to that reported in Ref. 15 but...
significantly lower than that reported in Ref. 5. Furthermore, it is surprising that the threshold-$I_{\text{EXC}}$ for the $X\text{–}X$ emission band is also very low, compared to that reported in Ref. 19 and 20. Indeed, Pan et al. has reported the $BX$ and $X\text{–}X$ emission bands from sol-gel ZnO powder, excited by a cw-He-Cd laser. This implies the high efficiency of biexciton formations and inelastic exciton–exciton scattering in the sol-gel sample. We tentatively interpret the low threshold-$I_{\text{EXC}}$ as being due to the nanocrystalline nature of the sample. When the crystal size is smaller than the Bohr radius of exciton (1.8 nm in ZnO) but larger than the excitonic coherence length, an exciton wave function can coherently extend over the nanocrystalline powders. This can lead to a large enhancement in the exciton oscillator strength. 21

In summary, we studied the PL of highly excited sol-gel ZnO nanopowders at low-$T$. The nonlinear emissions due to free biexciton transitions and inelastic exciton–exciton scattering were observed as the $I_{\text{EXC}}$ increases. We found that the threshold of the $I_{\text{EXC}}$ for the emergence of the nonlinear emission bands is low ($<18$ W/cm$^2$), indicating a high efficiency of exciton–exciton interactions in the sol-gel ZnO nanopowders.

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